

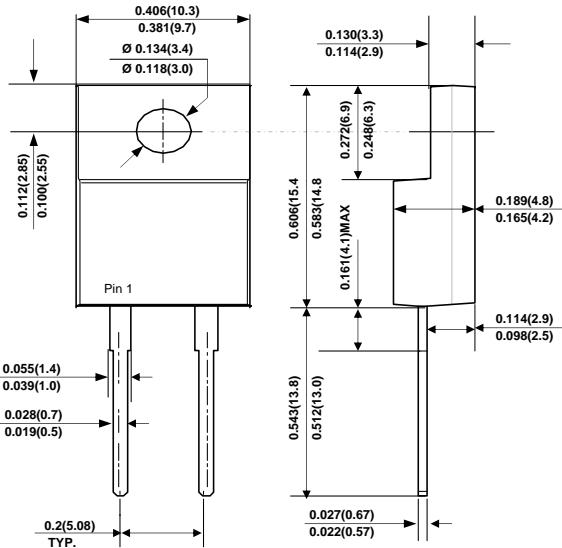


# UF800F THRU UF808F

## ISOLATION HIGH EFFICIENCY RECTIFIER

Reverse Voltage - 50 to 800 Volts Forward Current - 8.0 Ampere

### ITO-220AC



Dimensions in inches and (millimeters)

### FEATURES

- ◆ Plastic package has Underwriters Laboratory Flammability Classification 94V-0.
- ◆ Flame Retardant Epoxy Molding Compound.
- ◆ Exceeds environmental of MIL-S-19500/228
- ◆ Low power loss, high efficiency.
- ◆ Low forward voltage, high current capability.
- ◆ High surge capability.
- ◆ Ultra fast recovery times, high voltage.
- ◆ In compliance with EU RoHS 2002/95/EC directives.

### MECHANICAL DATA

**Case:** ITO-220AC, Molded plastic.

**Terminals:** Solderable per MIL-STD-750, Method 2026

**Weight:** 1.5615 grams.(0.055 ounces)

**Standard Packaging :** Tube.



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

PARAMETER	SYMBOLS	UF800F	UF801F	UF802F	UF804F	UF806F	UF808F	UNITS			
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	Volts			
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	Volts			
Maximum DC Breakdown Voltage	$V_{DC}$	50	100	200	400	600	800	Volts			
Maximum Average Forward Current at $T_C = 100^\circ C$	$I_{F(AV)}$	8.0						Amp			
Peak Forward Surge Current, 8.3ms single half sinewave superimposed on rated load(JEDEC method)	$I_{FSM}$	125						Amps			
Maximum Forward Voltage at 5A at $I_F=8.0A$	$V_F$	0.95		1.30	1.50	1.70	Volts				
Maximum DC Reverse Current Rated DC Blocking Voltage	at $T_J = 25^\circ C$ $T_J=100^\circ C$	$I_R$	10.0 100								
Maximum Reverse Recovery Time (NOTE 2)	$t_{rr}$	50			75			nS			
Typical Junction Capacitance (NOTE 1)	$C_J$	80			48			pF			
Typical Thermal Resistance (NOTE 3)	$R_{\theta JC}$	5.0						°C/W			
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150						°C			

**Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Reverse Recovery Test Conditions:  $I_F=0.5A$ ,  $I_R=1A$ ,  $I_{rr}=0.25A$ .

3. Thermal resistance from Junction to case.

4. Both Bonding and Chip structure are available.



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## RATINGS AND CHARACTERISTIC CURVES

FIG. 1- FORWARD CURRENT DERATING CURVE

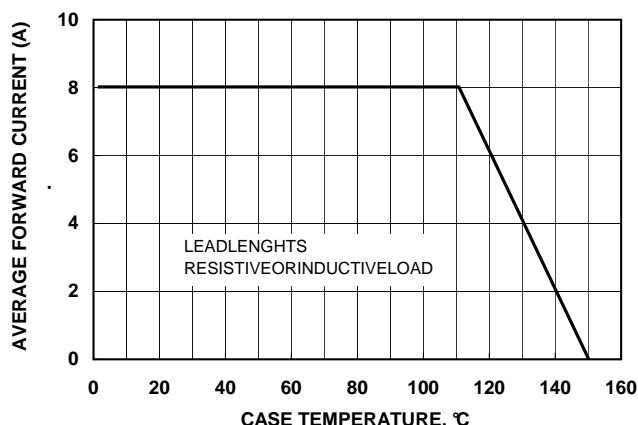


FIG. 2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

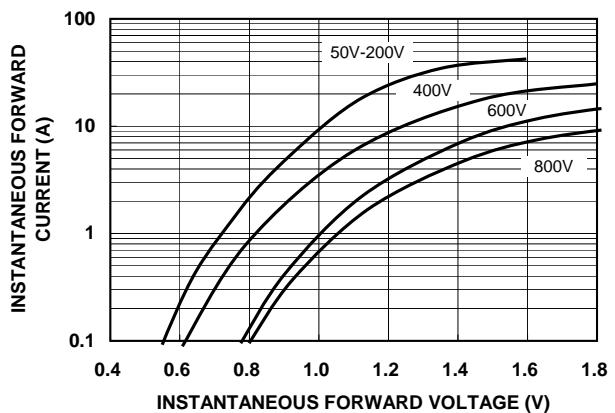


FIG. 3-TYPICAL REVERSE CHARACTERISTICS

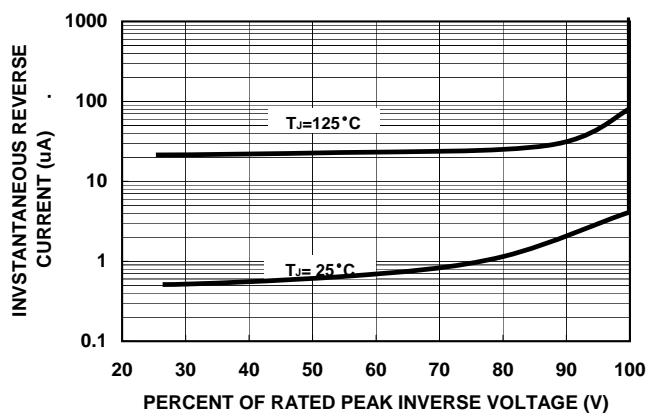


FIG. 4-MAXIMUM NON-REPETITIVE SURGE CURRENT

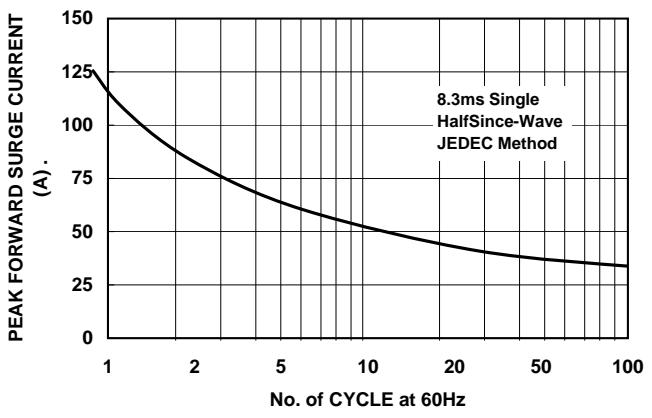


FIG. 5- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

